



King Mongkut's University of Technology Thonburi Midterm Examination

Semester 1 -- Academic Year 2013

Subject: EIE 326 Electronics Communication Engineering

For: Electrical Communication and Electronic Engineering, 3^{rd.} Yr. (Inter. program)

Exam Date: September 24th, 2013 Time: 09.00-12.00 AM.

Instructions:-

- 1. This exam consists of 6 problems with a total of 13 pages, including the cover.
- 2. Answer each problem on the exam. papers itself.
- 3. KMUTT 'rule compiled calculator is allowed.
- 4. Do not bring any exam papers and answer sheets outside the exam room.

Remarks:-

- Raise your hand when you finish the exam to ask for a permission to leave the exam
 room.
- Students who fail to follow the exam instruction might eventually result in a failure of the class or may receive the highest punishment with university rules.

Exam No.	1	2	3	4	5	6	7	8	TOTAL
Full Score									
Graded Score									

Name		Student ID		

Assistant Prof. Chanin Wongngamkam Tel: 9073

This examination has been approved by the committees of the ENE department.

(Assoc. Prof. Wudhichai Assawinchaichote, Ph.D.)
Head of Electronic and Telecommunication Engineering Department

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Name LD Class						
1.9. What type of noises is found in the HF communication?						
	b. atmospheric noise					
c. shot noise d. thermal noise						
1.10. Which one is not the product of non linear circ	cuit?					
a. L.O. frequency						
b. The sum of frequencies between LO and	b. The sum of frequencies between LO and RF					
c. Second harmonics of the LO. Frequency	measured at the mixer output.					
d. Second harmonics of the RF. Frequency	measured at the mixer output.					
1.11.For maximum power transfer						
a. source impedance and load impedance mu	st be equal					
b. source impedance must be lower than load	impedance					
c. source impedance must be higher than load	l impedance					
d. non of above is correct						
1.12 Which one is suitable for SSB amplifier	<i>,</i>					
a. Class A	b.Class B					
c.Class C	d.Class D					
1.13 What happen at the resonance frequency of a	series resonance circuit?					
a.Z of the circuit is highest.	b. Z of the circuit is lowest.					
c.Voltage across the LC has highest value. d.None of above is correct.						
1.14 What type of the oscillator is not suitable for	the Local Oscillator in the broadcasting receiver?					
a.Crystal oscillator	b.Colpitts oscillator					
c.Clapps oscillator	d.All of above is correct					
1.15 This is the benefits of having the carrier in A	M radio					
a. Detection in the receiver is possible with d	iode b. Can provide the AGC in the receiver					
c. Can provide the AFC in the receiver	d. All of above is correct.					
1.16. What is the detection range of Flip Flop type	phase detector?					
a. π	b. +/- π					
c. +/-2π	d no correct answer					
1.17.SSB filtering need this process						
a. Balanced modulation	b. very high Q filtering					
c. Low Q filter.	d. None of above is correct					
1.18. What is another name for the SSB detector						
a. Product detector b. Diode detector						
c. Peak detector	d. RF detector					
	3					

Name ID Class Instruction Mark "X" over the best choice in the given answer sheet (1 pt. each) 1.1. In EKG monitoring of some medical instrument. Which noise has to be concerned a. RFI noise b. Transit time noise c. 1/f noise d. none of above is correct 1.2 An AM wave with 150W of total power is fed into an 50 Ohms matched antenna. Calculate the power in each sideband if the modulation index is fixed at 1 25 W 33.3W 66.6 W d. none of above is correct c. 1.3. From above question, If the Modulation Index is 0.8 Recalculate for the power in each sideband. 12.12 W 13.12 W 18.18 W 15.10 W d. c. 1.4. Calculate power that can be reduced if the ambient temperature reduce from +27 to -243 Celsius 10 dB 11 dB b. c. 12 dB d. none of above is correct 1.5. In the series R,L,C circuit, what is the relationship of the Q factor to the circuit elements. a. Q is directly related to R/L b. Q is directly related to L/C d. none of above is correct c. Q is inversely related to R/L 1.6. Calculate the percentage modulation of the picture below a. 63 % b. 67 % c. 70 % d. none of above is correct 1.7. Which one is true for the adjustable crystal oscillator? a. series resonance b. anti resonance d. none of above is correct. c. between series and anti resonance 1.8. Which one is related to the efficiency? Unloaded Q b. Loaded Q d. Output impedance c. Input impedance

NameID	Class				
1.19.Describe the impedance of the crystal at frequency about	ove series resonance				
a. open circuit	b. short circuit				
c. inductive	d. capacitive				
1.20.Crystal oscillator is very stable unless					
a. induced by magnetic field	b. ambient temperature change				
c. induced by electric field	d. non of above is correct				
1.21 This diode need reverse bias to operate properly					
a. ring diode	b. diode detector				
c. varicap diode	d.rectifier diode				
1.22. What is value of T_o in order to find the Equivalent	noise temperature T_{eq} ?				
a. 273 K	b. 290K				
c. 300K	d. none of above is correct				
1.23. Double balanced mixer is suitable for					
a. AM modulator	b. SSB modulator				
c. Phase modulator	d. FM modulator				
1. 24. Which one is the frequency band that is suitable for s	space communication ?				
a .MF	b. HF				
c. VHF	d. UHF				
1.25. Which one is not the main made noise?					
a .Noise from the power line	b .Noise from the electrical bulb				
c. Noise from the running motor	d. Noise from the thunder				
1.26. What happen to the signal from this circuit?					
C = 0.0012µF CC = 0.1µF Fist Audio Audio Imput Fist C = 56kΩ					
a. Low frequency portion will attenuate	b. high frequency portion will attenuate				
c. Decreasing the noise	d .no correct answer				
1.27. Calculate the m, of the FM Broadcast transmitter with highest tone input?					
a. 3	b. 4				
c. 5	d. 6				
1.28. MC145152 can be used in the radio transmitter as ?					
a .IF amplifier	b. mixer				
c. Oscillator	d. No correct answer				
4					

NameID	Class
1.29. Calculate the noise voltage from 1MOhms resistor	at 1MHz and 30 celsius?
a .215 µ V	b. 129.39 μ V
c. 111 µ V	d .No correct answer
1.30. This parameter may come from the Local Oscillat	or ?
a .Harmonics content	b. Spurious frequencies
c. Noises sideband	d . All of above
1.31. Calculate the noise power at 1MHz and 30 celsius	, ?
a112.8 dBm	b113.8dBm
c110.5 dBm	d121.6dBm
1.32. Which one is the method of noise reduction?	
a .Decrease the bandwidth	b. Decrease the temperature
c. Decrease the input impedance	d. All of above
1.33. Which one is the non linear circuit	
a . AM modulator	b .SSB amplifier
c. RF amplifier	d .RF oscillator
The following figure is for Q.34 - 39	
REFERENCE OSC - R Iv FEEDBACK (In - N)	
PO _{out} A B C	HIGH IMPEDANCE
1.34. What will happen at time A?	,D , E v _L
a. PDout is equal to V _H	b. PDout is equal to V _L
c. PDout remain high impedance	d. No correct answer
1.35. What will happen at time B?	
a. PDout is equal to V _H	b. PDout is equal to V _L
c. PDout remain high impedance	d. No correct answer
1.36. What will happen at time D?	
a. PDout is equal to V_{μ}	b. PDout is equal to V_L
c. PDout remain high impedance	d. No correct answer
t.37. What will happen at time E?	
a. PDout is equal to V_H	b. PDout is equal to V_L
c. PDout remain high impedance	d. No correct answer

Name	m	Class
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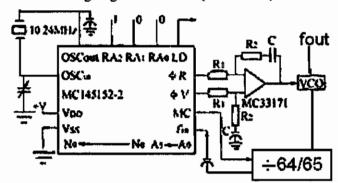
- 1.38. What kind of techniques used in this phase detector?
 - a. Logic AND

b. Analog multiplier

c. Exclusive or

- d. No correct answer
- 1.39. Compare PDout Voltage at time B and time C
 - a. Voltage at time B > V time C
- b. Voltage at time B = Vtime C
- c. Voltage at time B < V time C
- d. No correct answer

Use the following diagram to answer Q.1.40 - 1.48, M = 64



Refere	Total Divide		
RA2	RA1	Value	
0	D	0	8
0	ם ו	1 1	64
0	1	0	126
0	1	1 1	256
1	0	0	512
1	0	1 1	1024
1	1	0	1160
1	1	1 1	2048

- 1.40. This circuit utilized the technique called
 - a. Double loop frequency synthesizer
 - c. Dual modulus frequency synthesizer
- b. Single modulus frequency synthesizer
- d. No correct answer
- 1.41. Calculate for N if fout is 909.20 MHz

a.
$$N = 709$$

e.
$$N = 711$$

- b. N = 710
- d. No correct answer

1.42. Calculate for A if f_{out} is 909.20 MHz

a.
$$A = 11$$

c.
$$A = 31$$

b. A = 41

d.
$$A = 20$$

- 1.43. From Q41, Calculate maximum output frequency when N is fixed but A can be increased
 - a. 909.20 MHz

b. 910.06 MHz

c. 919.00MHz

d 918.86 MHz

- 1.44. If the loop will lock within 3 periods of the f_{ee} What is this value?
 - a. 50 microsecond

b. 150 microsecond

c. 50 millisecond

d 5 millisecond

1.45. Where is the Hi -Z point in the circuit?

a. at MC pin

b. at Op-Amp. Input pin

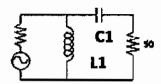
c. at VCO input pin

d no correct answer

Name	3			Class
1.46.	What is the pur	pose of the series R2+C?		
	a. boost the	frequency response of the loop	b.	decrease the 50 Hz interference
	c. decrease	20 KHz interference	d	decrease 1.024 MHz interferenc
1.47.	What is the total	I divided no. of this circuit?		
	a. MA		b.	NM+A
	c. M A+(N-	1)	d.	NA+M
1.48.	What is the cou	nting number at the beginning of the	cou	nt?
	a. MA		b.	NM+A
	c. M A+(N-	1)	d.	NA+M
1.49.	What is the ch	aracteristic only found in FM radio	•	
	a .single sid	leband	b.	suppressed carrier
	c. Capture	effect	d.	Has large carrier
1.50.	Compare -100	dBm and 1 x 10 ⁻⁶ V _{rms} for a 50 Oh	ms l	oad?
	a. Can't con	mpare different units	b.	-100 dBm is bigger
	c100 dBr	n is smaller	d.	they are equal
1.51	Which one is th	e condition called "Barkhausen crite	ria '	'?
	a.loop gain a	amplitude = 3	b.	loop phase shift = 2π
	c.loop phase	shift = π	d.	None of above
1.52	Which amplifie	or circuit has high current gain?		
	a. Common	collector	b.	Common base
	c. Common	emittcr	d.	Push-pull complementary
1.53	Which amplifie	er eircuit has high power gain?		
	a. Common	eollector	b.	Common base
	c. Common	emitter	d.	Push-pull complementary
1.54	Which amplifie	er circuit has output with phase revers	al?	
	a. Common	collector	b.	Common base
	c. Common	emitter	d.	Push-pull complementary
1.55	Which amplifie	er circuit has high input resistance?		
	a. Common	collector	b.	Common base
	c. Common	emitter	d.	Push-pull complementary
1.56	Which amplifie	er circuit has input between B-E and o	utpi	ut between C-E?
	a. Common	collector	b.	Common base
	c. Common	emitter	d.	Push-pull complementary

1.57 Which amplifier circuit utilized both NPN a	DClass
	and PNP transistor?
a. Common collector	b. Common base
c. Common emitter	d. Push-pull complementary
1.58 Which amplifier circuit has low input resist	ance?
a. Common collector	b. Common base
c. Common emitter	d. Push-pull complementary
1.59 Which one has widest detection range?	
a. Analog switch type	b. AND gate
c. RS flip flop	d. PFD
1.60 Calculate the Carson's bandwidth of the a ba	roadcast FM station when the maximum deviation of 75
$\ensuremath{\text{KHz}}$ and maximum input frequency is 15 $\ensuremath{\text{KHz}}$.	
a. 15 KHz	b. 190 KHz
c. 150 KHz	d. 180 KHz

3. From the matching circuits below when $R_s = 600$ Ohms and X_p is an inductor.



Calculate the values of L and C that produce the specified reactance at 30MHz. by using these formulas.(10 points)

$$Q_S = Q_P = \sqrt{\frac{R_{Larger}}{R_{smaller}} - 1}$$

$$L_1 = \frac{X_L}{\omega_0} = \frac{Q_S R_{smaller}}{\omega_0} = \frac{R_{Larger}}{\omega_0 Q_P}$$

$$C_1 = \frac{1}{\omega_0 X_C} = \frac{1}{\omega_0 Q_S R_{smaller}} = \frac{Q_P}{\omega_0 R_{Larger}}$$

4. Fill in the blanks or answer the question (10 points)

4.1. Given

 \boldsymbol{E}_{c} is the peak voltage of the carrier before modulation

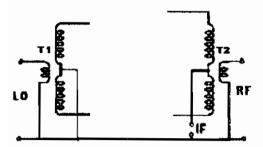
 Θ_c and Θ_M stand for carrier frequency and modulating frequency

 m_r is the modulation index for FM

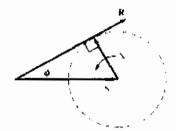
Write down the Instantaneous Voltage of FM signal below (3 points)

Name......D.....Class.....

4.2. Complete the schematic diagram of the Double balance mixer below (3 points)

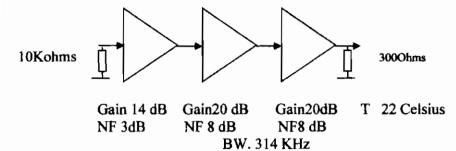


- 4.3. The electric field strength (rms) at a receiving station is 10 \$\mu V/m\$. Calculate
- (a) the magnetic field strength; (2 points)
- (b) the amount of power incident on a receiving aerial with an effective area of 1 m² (2 points)
- 5. Explain the relationship between noise and FM signal from this figure (5 points)



Name	ID	Close
Name	LD	

- 6. From the following information
- a) Calculate the noise voltage and power at the input and output of the system (3 points)
- b) overall noise figure of the system (2 points)



Formulas

$$P_n = kT\Delta f$$

$$e_n = \sqrt{4kT\Delta f R}$$

$$i_n = \sqrt{2qI_{dc}\Delta f}$$

%m =
$$(B-A/B+A) \times 100\%$$
 or %m = $(E_i/E_c) \times 100\%$

Sin A Sin 8 - 1/2cos(A-8) - 1/2 cos(A+8)

Cos A Cos B = 1/2cos(A+B) - 1/2 cos(A-B)

$$Z_{left} = R_{left} + jX_{left} = \frac{1000jX_p}{1000 + jX_p} = \frac{(1000jX_p)(1000 - jX_p)}{(1000 + jX_p)(1000 - jX_p)}$$

$$\frac{X_L}{R_{SOUTCe}} = \frac{R_{load}}{X_C}$$

$$m = \frac{E_I}{E_m}$$

$$e = E_c \sin \omega_c t + \frac{mE_c}{2} \cos(\omega_c - \omega_I)t - \frac{mE_c}{2} \cos(\omega_c + \omega_I)t$$

$$E_{SF} = \frac{mE_c}{2}$$

$$P_I = P_c (1 + \frac{m^2}{2})$$

B.W._{carron.} =
$$2(\Delta f + f_m) = 2\Delta f + 2f_m$$

NR = NR₁ + (NR₂ - 1)/PG₁ + (NR₃ - 1)/PG₁.PG₂ noise ratio

$$\Delta f = \phi_{rad} x f_m$$
frequency deviation from noise